N-Channel JFET 30 V, 1.2 to 3.0 mA, 5.0 mS, SOT-883

TF412S

Features

- Small IGSS: Max -1.0 nA (V_{GS} = -20 V, V_{DS} = 0 V)
- Small Ciss: Typ 4 pF (V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz)
- Ultrasmall Package Facilitates Miniaturization in End Products
- This is a Pb-Free and Halogen Free Device

Applications

• Low-Frequency General-purpose Amplifier, Impedance Conversion, Infrared Sensor Applications

Specifications

ABSOLUTE MAXIMUM RATINGS (at Ta = 25°C)

Symbol	Parameter	Value	Unit
V _{DSX}	Drain-to-Source Voltage	30	V
V _{GDS}	Gate-to-Drain Voltage	-30	V
I _G	Gate Current	10	mA
I _D	Drain Current	10	mA
PD	Power Dissipation	100	mW
Тj	Junction Temperature	150	°C
Tstg	Storage Temperature	–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

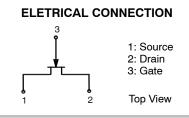
NOTE: This product is designed to "ESD immunity < 200 V*", so please take care when handling.

* Machine Model



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SOT-883 (XDFN3) CASE 506CB

MARKING DIAGRAM



= Specific Device Code A2 Μ

= Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
TF412ST5G	SOT-883	8.000 Tape / Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

TF412S

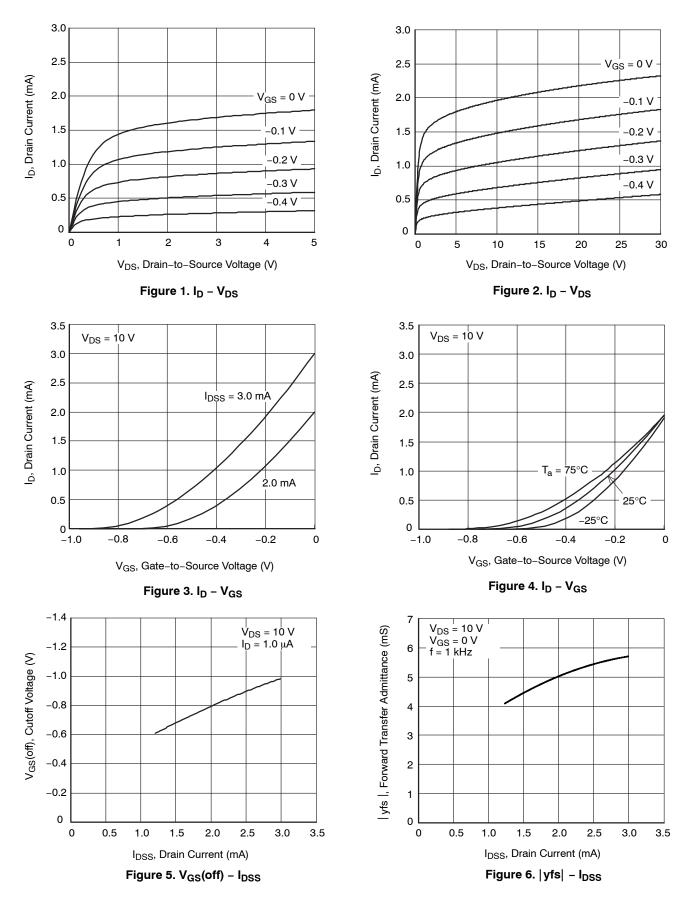
ELECTRICAL CHARACTERISTICS (at $T_A = 25^{\circ}C$)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)GDS}	Gate-to-Drain Breakdown Voltage	$I_{G} = -10 \ \mu A, \ V_{DS} = 0 \ V$	-30			V
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$			-1.0	nA
V _{GS} (off)	Cutoff Voltage	V_{DS} = 10 V, I_D = 1 μ A	-0.18	-0.80	-1.5	V
I _{DSS}	Drain Current	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}$	1.2		3.0	mA
yfs	Forward Transfer Admittance	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 kHz	3.0	5.0		mS
Ciss	Input Capacitance	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz		4		pF
Crss	Reverse Transfer Capacitance]		1.1		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TF412S

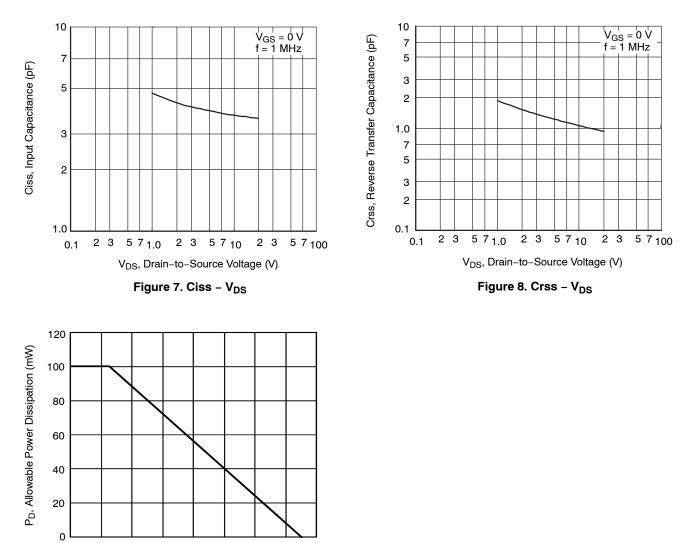
TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS (continued)



0

20

40

60

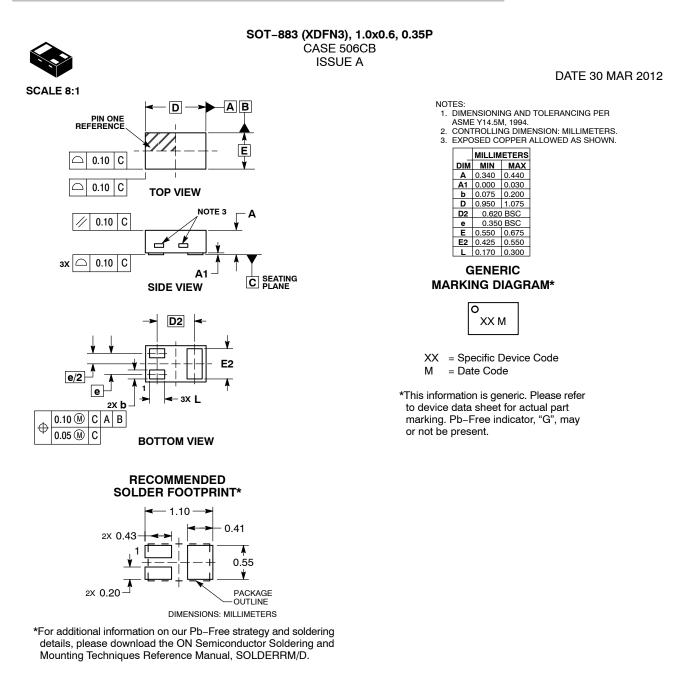
80

Ta, Ambient Temperature (°C) Figure 9. P_D – Ta

100 120

140 160





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